

Organic photosensors for detection of VUV scintillation light

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Motivation

- Light collection for next-generation noble element detectors
 - Push for larger detector sizes means more areal coverage needed.
 - Need large areal coverage to up $\sim 1000 \text{ m}^2$
 - Ideally, direct VUV sensitive
 - Simultaneous collection of light and charge helpful for pixelated TPC readout schemes
- *Need:*
 - Large-area **low-cost** VUV photosensors
- VUV detectors approaches
 - PMTs with WLS, VUV SiPMs, light traps, GaN, etc...
 - Amorphous selenium (See talk by Jonathan Assadi)
 - Organic semiconductors (This talk!)

Collaborators:

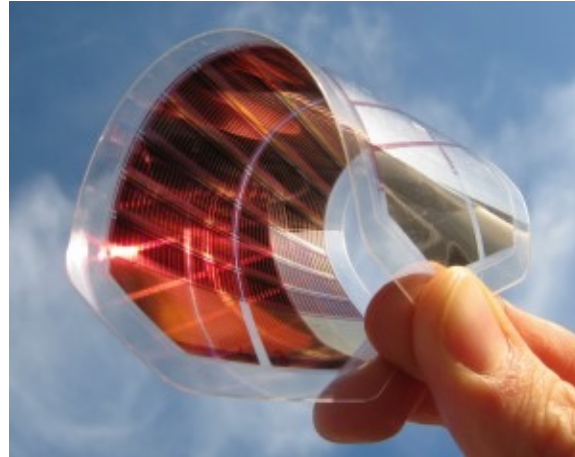
- Sabrina Cheng (ORNL),
- Kate Hausladen (ORNL),
- Austin McDonald (UTA),
- Jonathan Asaadi (UTA)

Organic semiconductors for (VUV) photon detection?



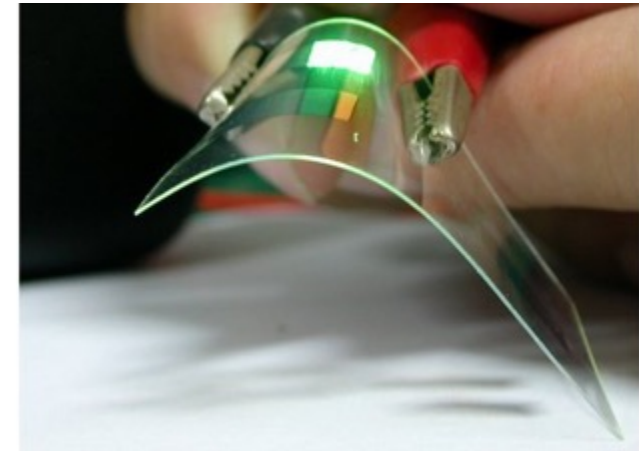
<https://www.theengineer.co.uk/printed-perovskite-solar-cells/>

Additive manufacturing



<https://3dprint.com/1666/scientists-3d-print-new-solar-panels-which-work-best-when-cloudy/>

Solar energy



<https://www.evolving-science.com/matter-energy-materials/powering-future-one-step-closer-organic-electronics-our-homes-00165>

**Organic LEDs (OLEDs)
and organic photosensors**

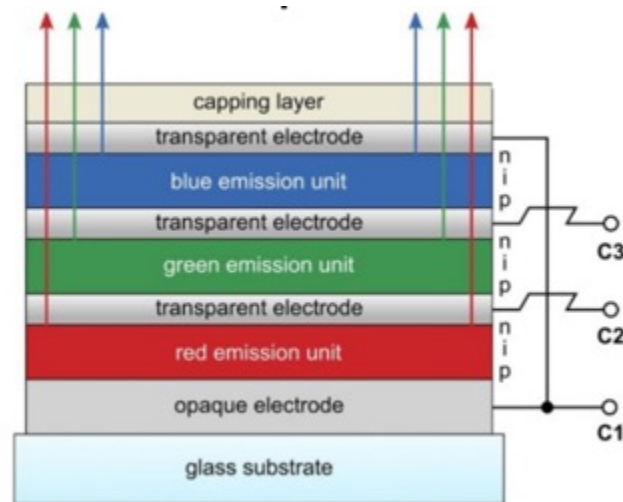
Vast amount of knowledge exists – Can it be adapted for high energy physics experiments?

Interesting opportunities....

- Organic semiconductors
 - Low cost & highly scalable
 - Roll-to-roll printing production > 100 m scale
 - Industry driven technology
 - Cell phones, OLED displays, sensors for medical devices
- Can be made on rigid and flexible substrates
- Stackable geometry for spectroscopic (multicolor) readout
 - No loss of photosensor coverage
 - Cherenkov vs scintillation separation?



<https://www.sammobile.com/news/samsungs-new-foldable-and-udc-panels-reveal-an-exciting-future/>



<https://www.nature.com/articles/s41598-018-27976-z>

Stacked OLED

Stacked OPD

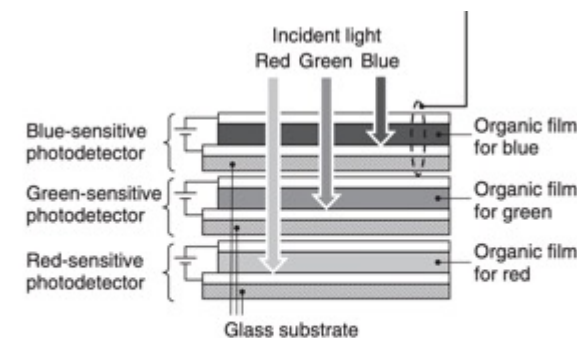
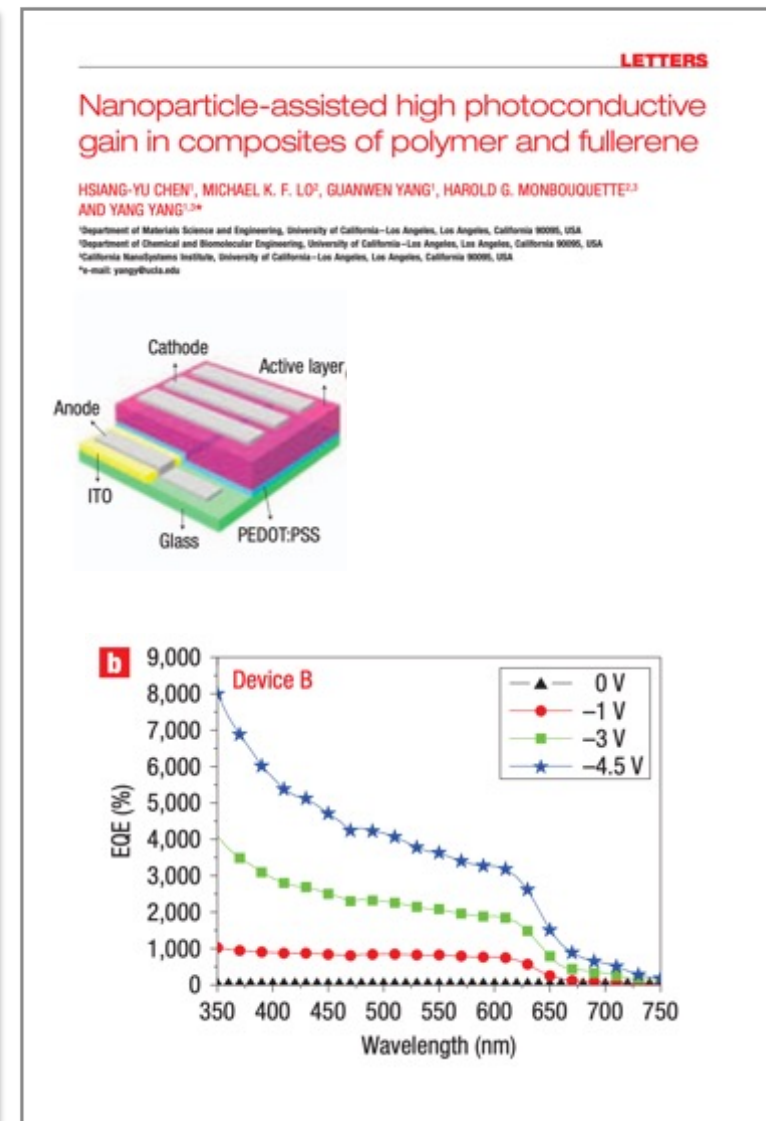
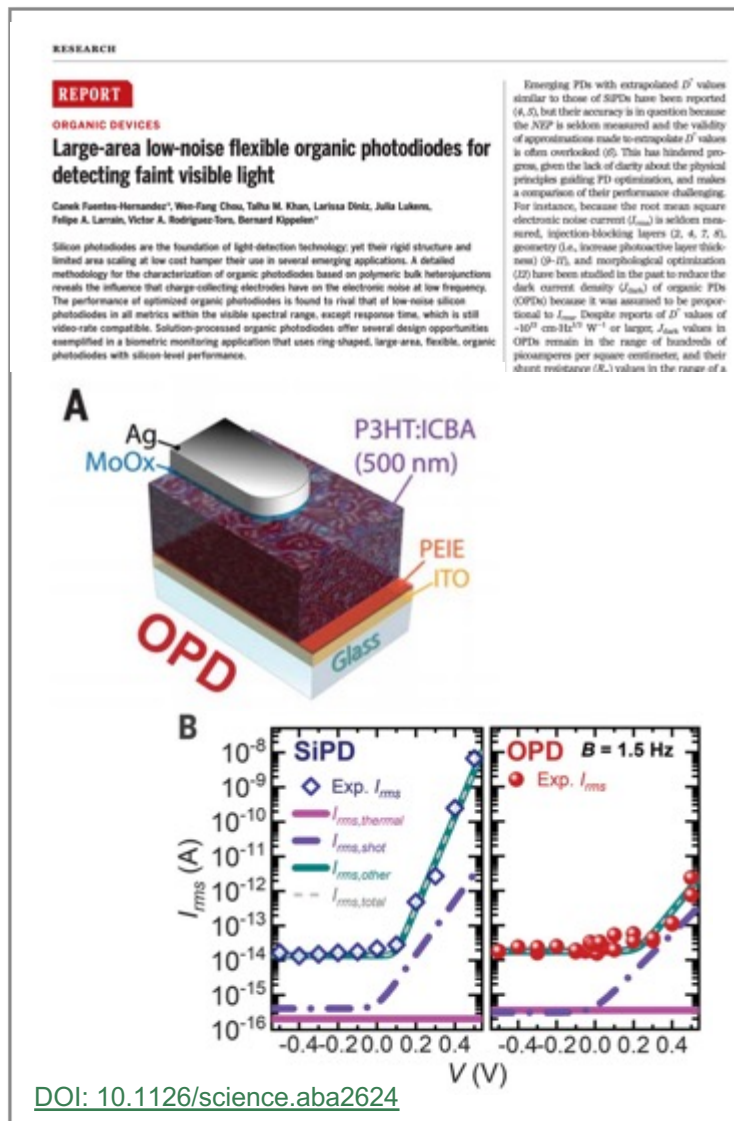


Fig. 1. Schematic diagram of stack structure and cross sectional view of a photodetector.

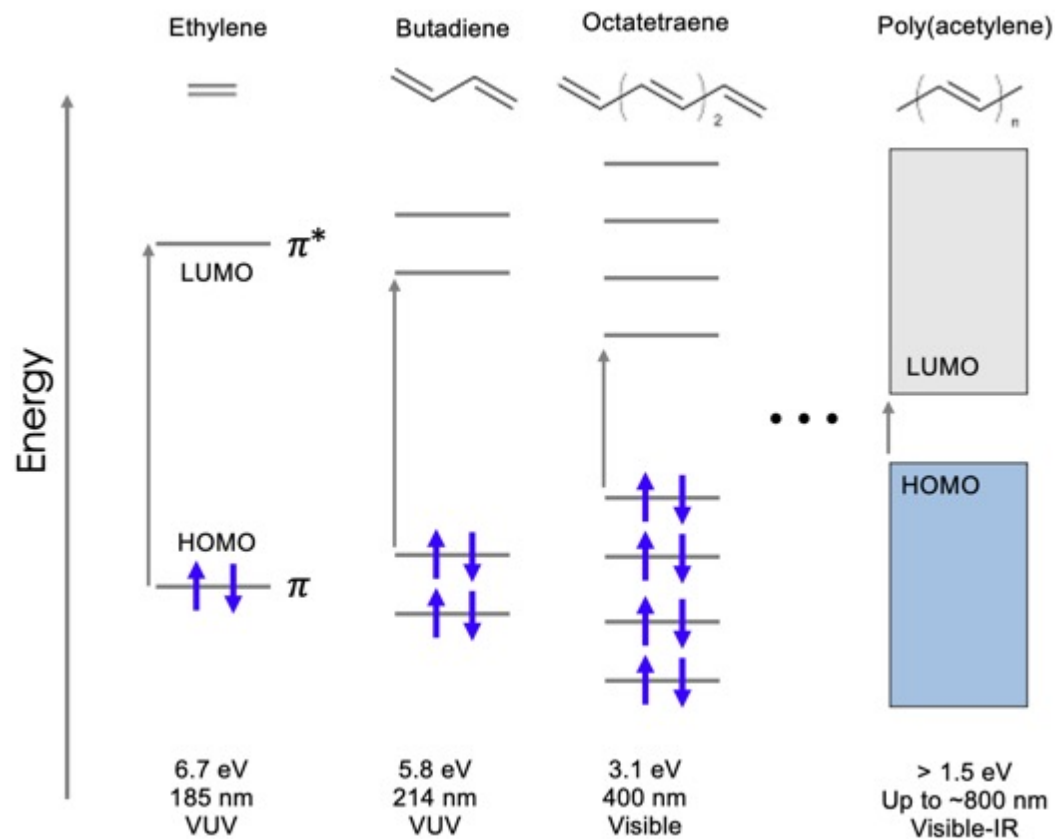
What about dark current and gain?

- Organic photodiodes (OPD) have reached the dark current of Si photodiode technologies
 - P3HT:ICBA based OPD have reached dark currents $I_{rms} < 0.1$ pA
- Ongoing research exploring gain-mechanisms in photo photodiodes
 - External quantum efficiencies $> 100\%$
 - Photons in \rightarrow electrons out
- Challenges with OPDs
 - Slow response time
 - Cryogenic operation?
 - Long term stability?

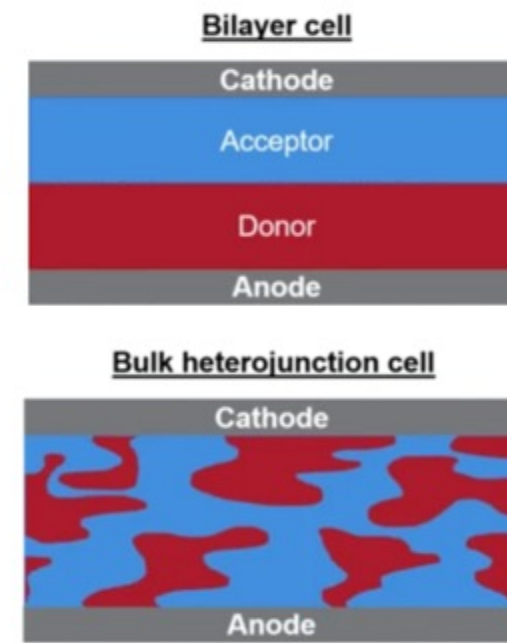


Organic semiconductors?

- Increasing conjugation leads to formation of quasi-continuous 'bands'
- Short exciton diffusion length restricts thickness in planer geometry to ~ 10 nm
 - Thin thickness limits photo absorption in planer geometries
- Bulk heterojunction (BHJ) geometry
 - P-type & n-type semiconductor materials are blended together
 - Allows for thicker photosensor geometries

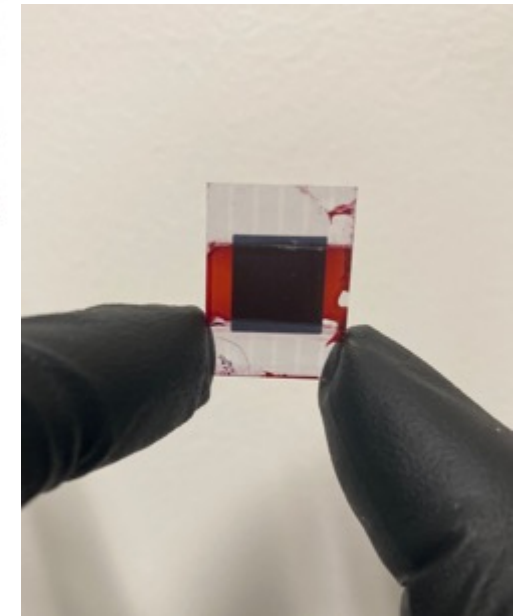
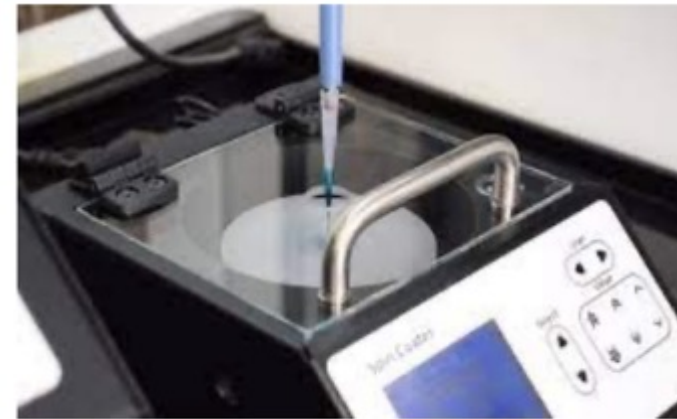


Optical band gap is highly tunable through molecular design

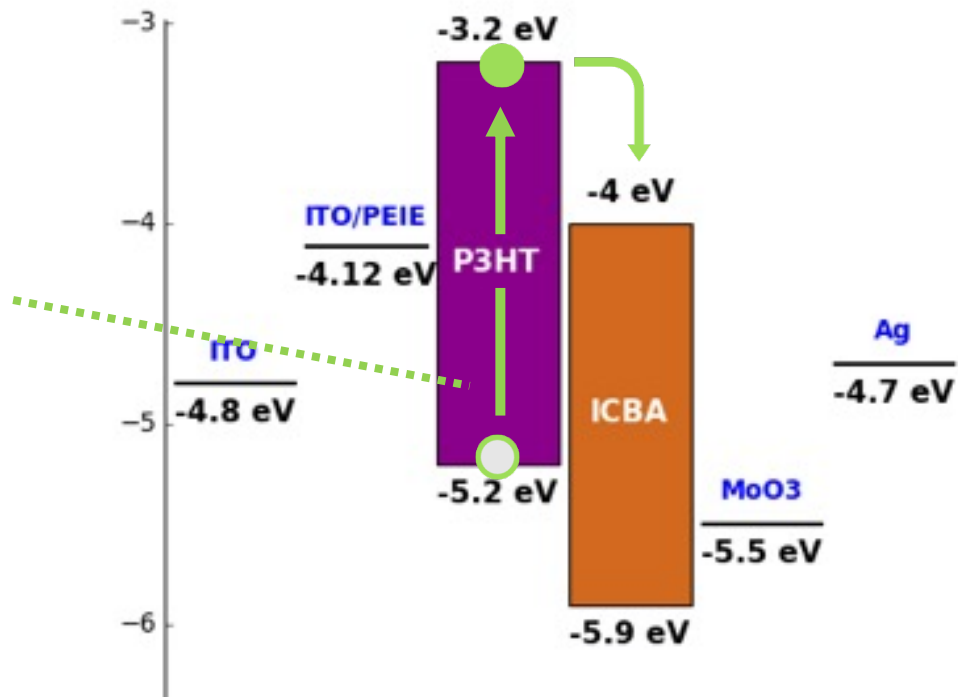


Fabrication of organic photodiodes

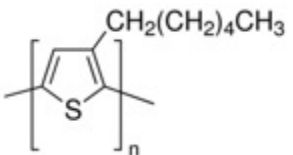
- Sputter coating of ITO anode layer
 - Transparent electrical conductor
- Cleaning of substrates
 - Sonicate and UV-ozone treatment
 - Improves wettability
- Apply photoactive layer
 - Spin coating
 - Can also use slot die for roll-to-roll
 - Applicable to 100+ meter scale production
- Thermal evaporation of metallic cathode



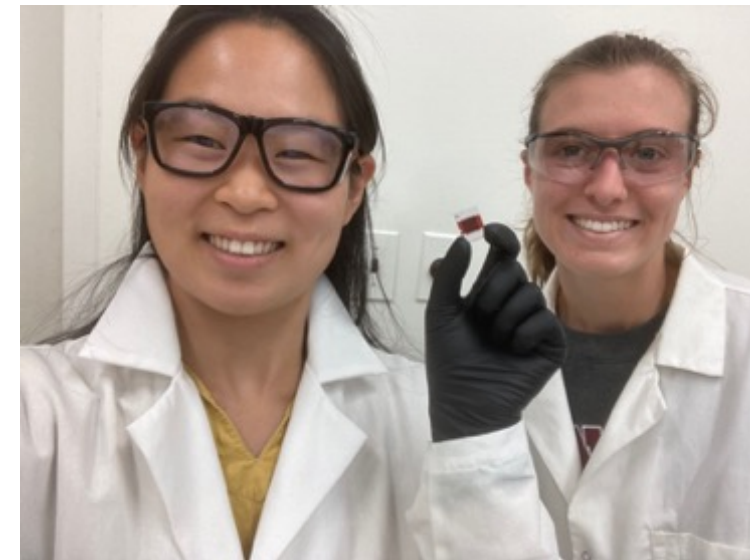
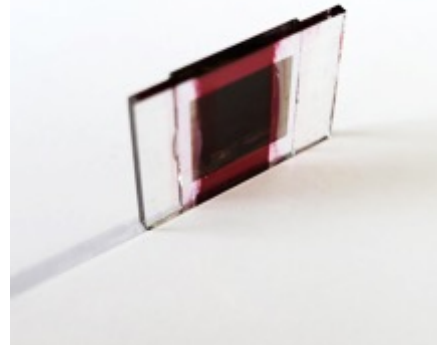
Organic photodiode



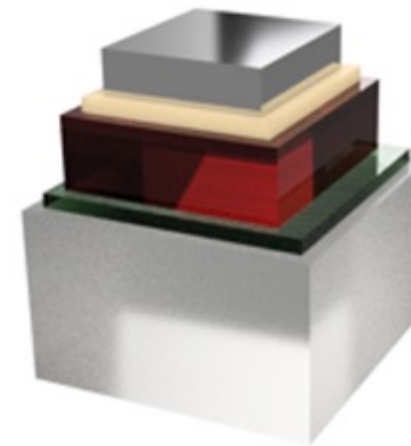
P3HT
Electron donor
(n-type)



ICBA
Electron acceptor
(p-type)



ORNL Summer Interns – Sabrina Cheng & Kate Hausladen hold their first functional OPD



Ag (200 nm)
MoO_x (10 nm)
P3HT:ICBA (500 nm)
PEIE (10 nm)
ITO on Glass

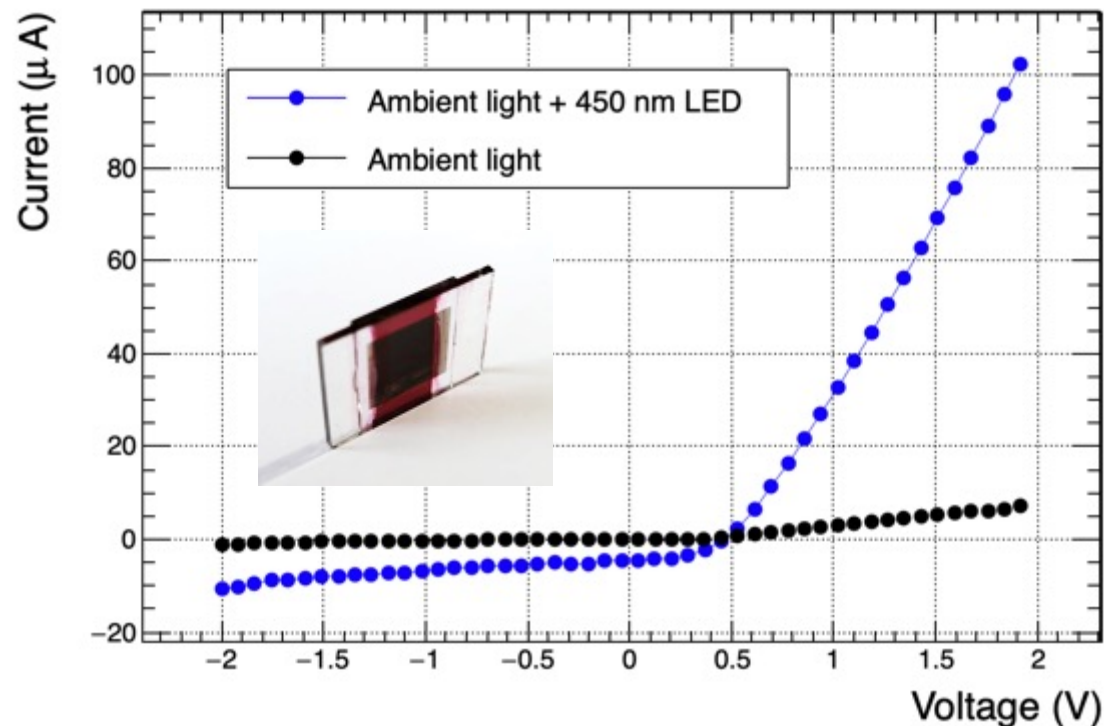
*Nominal P3HT:ICBA thickness.
Thickness measurements in progress

Substrate – glass
Anode – ITO / PEIE
Photoactive layer – P3HT:ICBA
Cathode – Ag / MoO_x

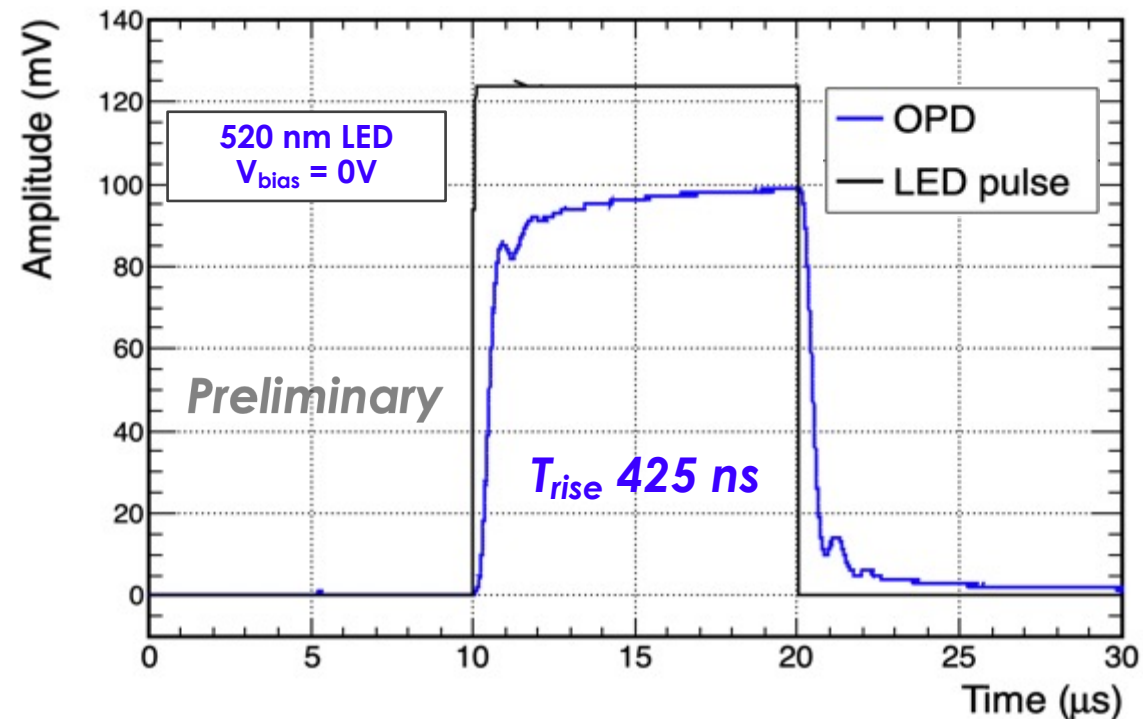
Results

- First batch of P3HT:ICBA OPDs ***It works!***

I-V curve



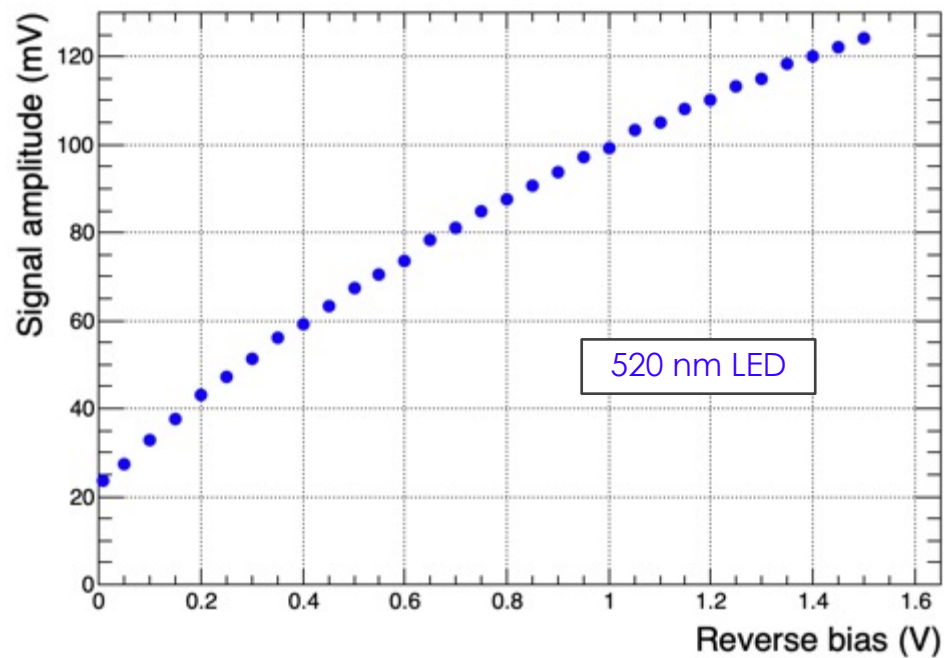
Timing response



Slower response time compared to SiPM or PMTs. For fast timing applications, OPDs can be used in combination with faster detectors

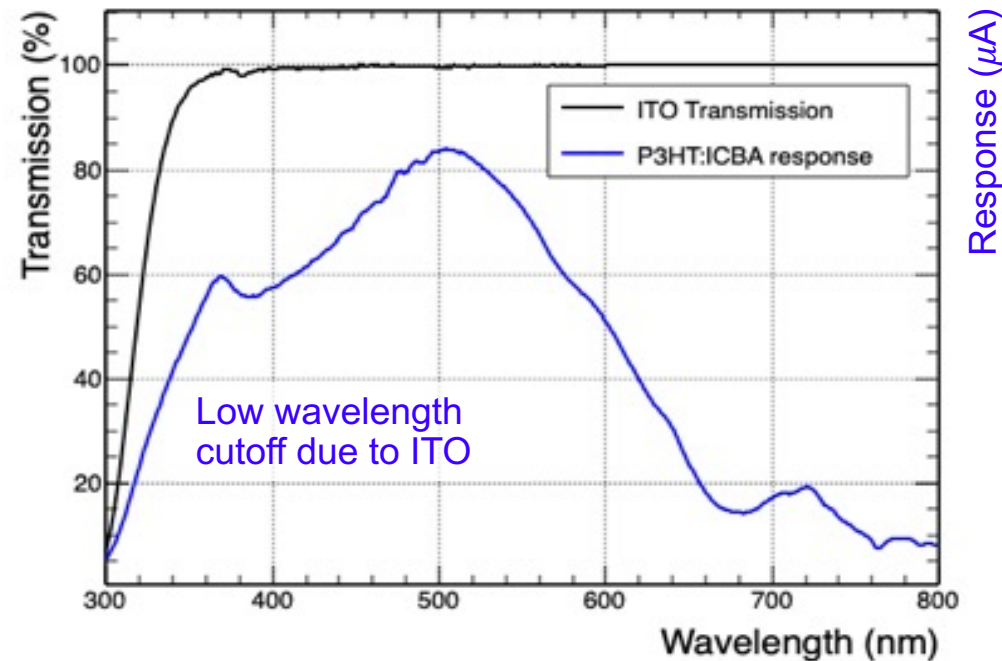
Results

Signal Amp vs bias



Can operate in reversed bias mode or photoconductor mode

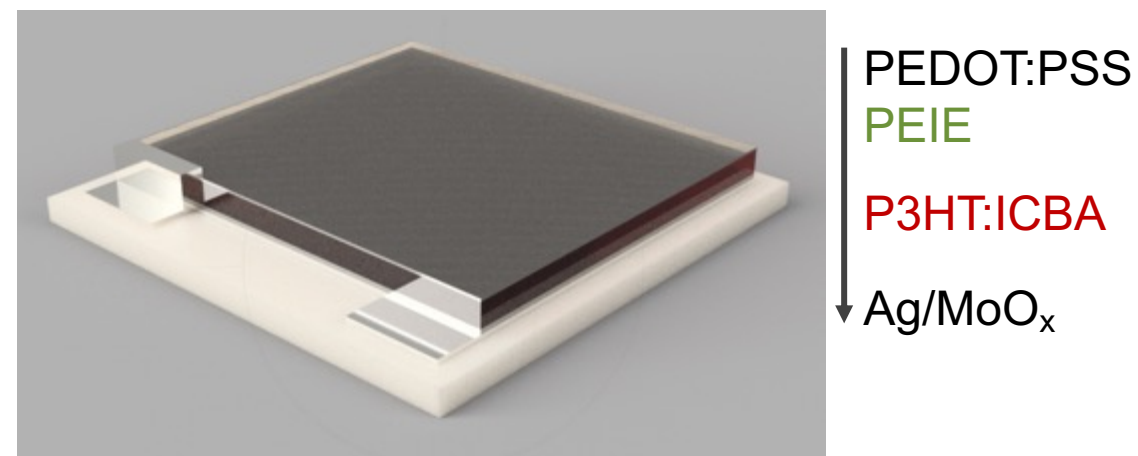
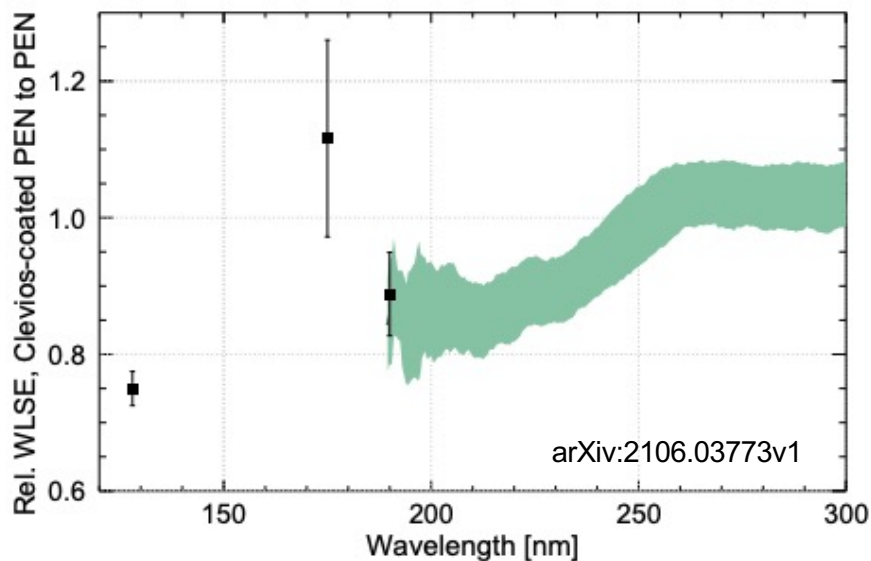
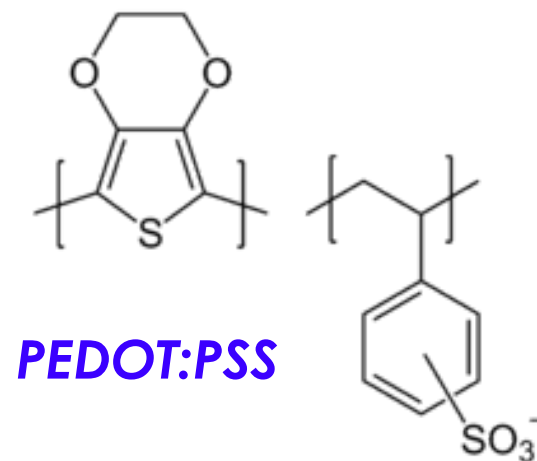
Spectral sensitivity



ITO limits the lower wavelength of OPD!

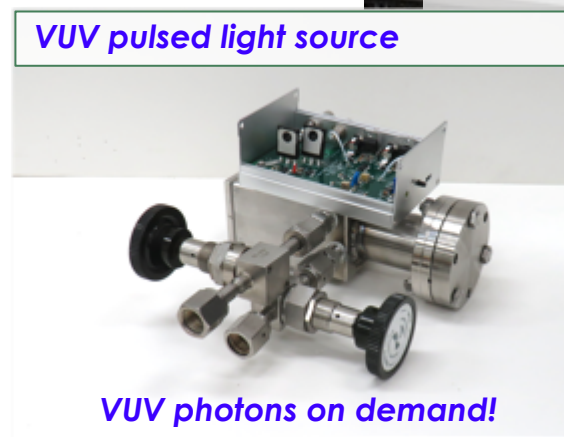
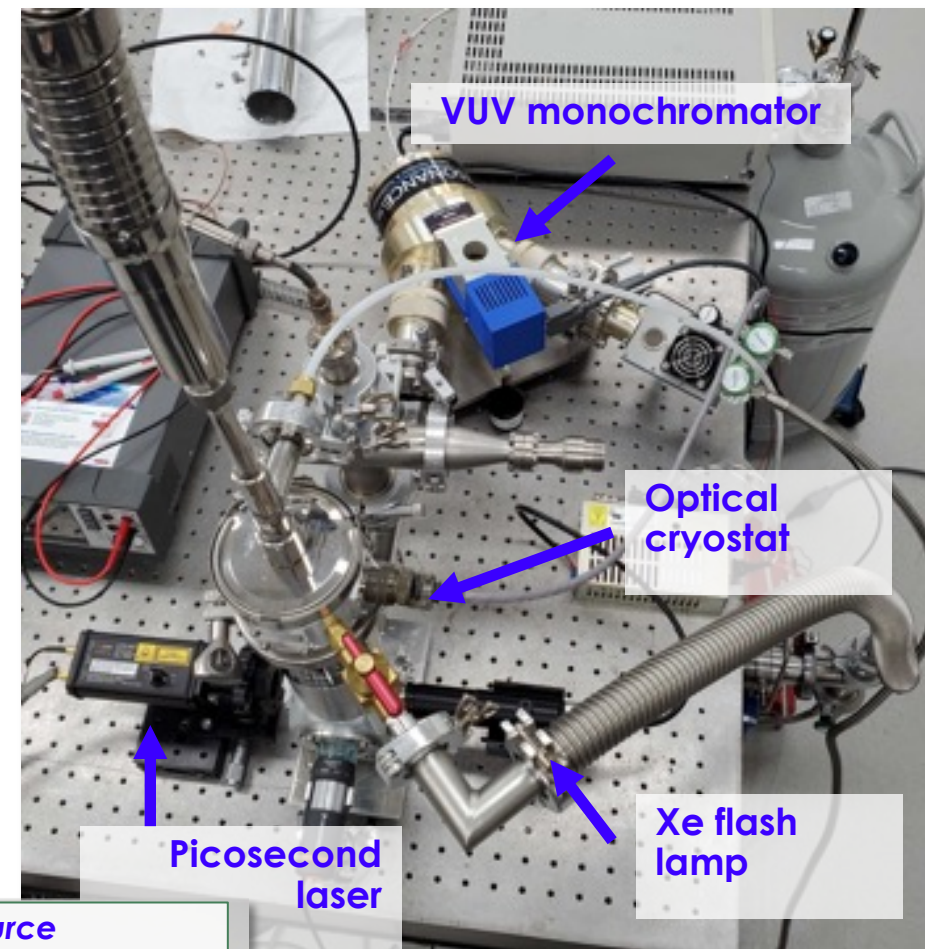
R&D on VUV transparent conductors

- Challenge for VUV sensors is requirement to have a VUV transparent conductor
 - Critical component for planer geometry VUV sensors
 - Functions as a VUV window and electrode
- Recent results indicate PEDOT:PSS may function as a transparent conductor for VUV light.
- Possible solution – invert assembly procedure with transparent conductor material such as PEDOT:PSS



Conclusion and next steps...

- Organic photodiodes may serve as an attractive option for next-generation experiments
 - Low-cost, scalable technology
 - Ability to create stackable spectroscopic photosensors
- Low temperature & VUV wavelength testing in progress
- Newly developed VUV sensor evaluation platform
 - Wavelength range: 58 – 3200 nm
 - Temperature range: 5 – 500 K
- Light sources
 - Windowless plasma lamp
 - Newly developed 128 nm pulsed light source
 - Adjustable intensity – ~10k to single photon level
 - **See talk by Austin McDonald on Friday!**



Thank you